TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX273F,TC74LCX273FW,TC74LCX273FT

Low-Voltage Octal D-Type Flip-Flop with Clear with 5-V Tolerant Inputs and Outputs

The TC74LCX273F/FW/FT is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low-power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

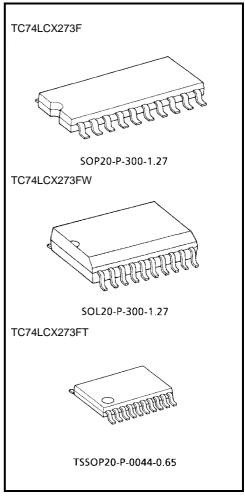
This 8 bit D-type flip-flop is controlled by a clock input (CK) and a clear input ( $\overline{CLR}$ ). When the  $\overline{CLR}$  input is low, the eight outputs are at a low logic level.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

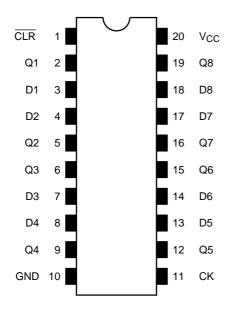
- Low-voltage operation: V<sub>CC</sub> = 2.0 to 3.6 V
- High-speed operation:  $t_{pd} = 8.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 273 type

Note: xxxFW (JEDEC SOP) is not available in Japan.

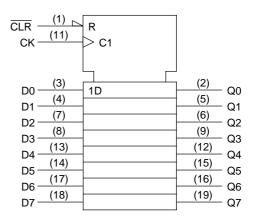


Weight SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

# Pin Assignment (top view)



#### **IEC Logic Symbol**

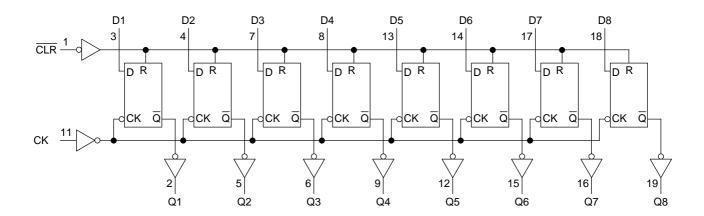


### **Truth Table**

	Inputs		Outputs	Function
CLR	D	CK	Q	Tariction
L	Х	Х	L	Clear
Н	L		L	_
Н	Н		Н	_
Н	Х	$\neg$	Qn	No change

X: Don't care

### **System Diagram**





### **Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
		(Note 2)	
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	lok	±50 (Note 3)	mA
DC output current	I <sub>OUT</sub>	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1:  $V_{CC} = 0 V$ 

Note 2: High or low state.  $I_{\mbox{OUT}}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND, V_{OUT} > V_{CC}$ 

### **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	٧	
Power supply voltage	v CC	-1.5 to 3.6 (Note 4)		
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 5)	V	
Output voltage	VOU1	0 to V <sub>CC</sub> (Note 6)	V	
Output current	1/1	±24 (Note 7)	mA	
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±12 (Note 8)		
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V	

Note 4: Data retention only

Note 5:  $V_{CC} = 0 V$ 

Note 6: High or low state

Note 7:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 8:  $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$ 

Note 9:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



#### **Electrical Characteristics**

### DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test Condition			Min	Max	Unit
		Cymbol	rost condition		V <sub>CC</sub> (V)	IVIIII	IVIAX	Offic
Input voltage	H-level	V <sub>IH</sub>				2.0	_	V
input voitage	L-level	V <sub>IL</sub>				_	0.8	V
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	_	V
	H-level	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
Output voltage  L-level				I <sub>OH</sub> = -18 mA	3.0	2.4	_	
				I <sub>OH</sub> = -24 mA	3.0	2.2	_	
	I level	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2		
			I <sub>OL</sub> = 12 mA	2.7	_	0.4		
	L-ievei	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 16 mA	3.0	_	0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.55	
Input leakage cur	rent	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V	V <sub>IN</sub> = 0 to 5.5 V		_	±5.0	μΑ
Power-off leakage	current	l <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	10.0	μΑ
Quiescent supply current		Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	_	10.0	
			V <sub>IN</sub> = 3.6 to 5.5 V	2.7 to 3.6	_	±10.0	μΑ	
Increase in Icc per input		Δlcc	$V_{IN} = V_{CC} - 0.6 \text{ V}$	2.7 to 3.6	_	500		

# AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Symbol	Test Condition		Min	Max	Unit
			V <sub>CC</sub> (V)			
Maximum clock frequency	$f_{MAX}$	(Figure 1, Figure 2)	2.7	_	—	MHz
Waximum oleok nequency	IVIAA	(rigure 1, rigure 2)	$3.3 \pm 0.3$	150	_	IVII IZ
Propagation delay time (CK-Q)	t <sub>PLH</sub>	(Figure 1, Figure 2)	2.7	_	9.5	ns
Tropagation delay time (Or Q)	t <sub>PHL</sub>	(Figure 1, Figure 2)	$3.3 \pm 0.3$	1.5	8.5	ris
Propagation delay time ( CLR -Q)	tn	(Figure 1, Figure 3)	2.7	_	9.5	nc
Propagation delay time (CLR -Q)	t <sub>PHL</sub>	(Figure 1, Figure 3)	$3.3 \pm 0.3$	1.5	8.5	ns
Minimum pulse width (CK)	t <sub>w (H)</sub>	(Figure 4 Figure 2)	2.7	3.3	_	
	t <sub>w (L)</sub>	(Figure 1, Figure 2)	$3.3 \pm 0.3$	3.3	_	ns
M: :	t <sub>w (L)</sub>	(Figure 2)	2.7	3.3	_	- ns
Minimum pulse width (CLR)		(Figure 3)	$3.3 \pm 0.3$	3.3	_	
Minimum actus time		(Figure 4 Figure 2)	2.7	2.5	_	
Minimum setup time	t <sub>S</sub>	(Figure 1, Figure 2)	$3.3 \pm 0.3$	2.5	_	ns
Minimum hold time		(Figure 4 Figure 2)	2.7	1.5	_	
Minimum noid time	t <sub>h</sub>	(Figure 1, Figure 2)	$3.3 \pm 0.3$	1.5	_	ns
	_	(5: 4)	2.7	2.5	_	
Minimum removal time	t <sub>rem</sub> (Figure 4)		$3.3 \pm 0.3$	2.0	_	ns
	t <sub>osLH</sub>	AL	2.7	_	_	
Output to output skew	t <sub>osHL</sub>	(Note 10)	$3.3 \pm 0.3$	_	1.0	ns

Note 10: Parameter guaranteed by design.  $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, \, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

### **Dynamic Switching Characteristics**

(Ta = 25°C, input:  $t_r = t_f = 2.5 \text{ ns}$ ,  $C_L = 50 \text{ pF}$ ,  $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	$V_{IH}=3.3\;V,\;V_{IL}=0\;V$	3.3	8.0	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>			3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_		0	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note 11)	3.3	25	pF

Note 11: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$ 

#### **AC Test Circuit**

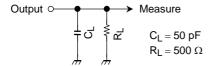


Figure 1

#### **AC Waveform**

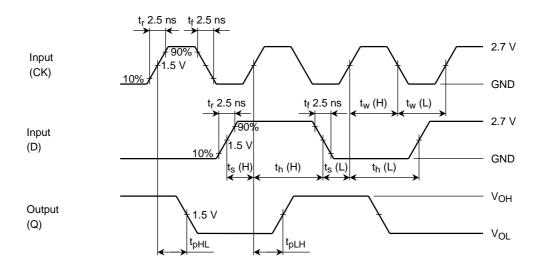
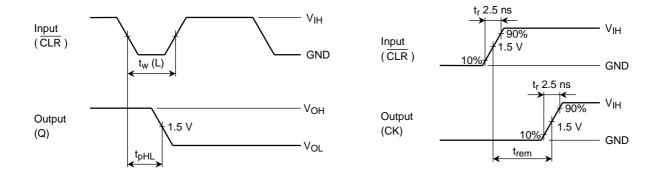


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>, t<sub>w</sub>, t<sub>s</sub>, t<sub>h</sub>



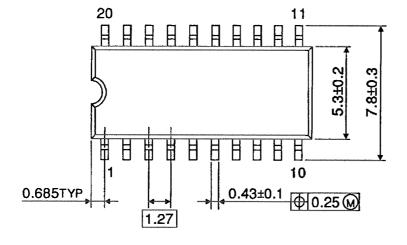
6

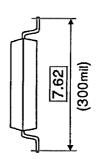
Figure 3 t<sub>pHL</sub>

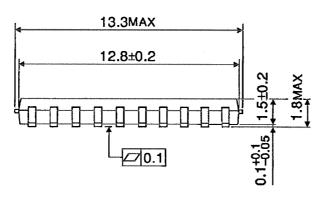
Figure 4 t<sub>rem</sub>

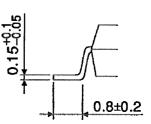
# **Package Dimensions**

SOP20-P-300-1.27 Unit: mm





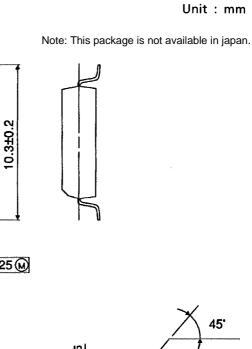


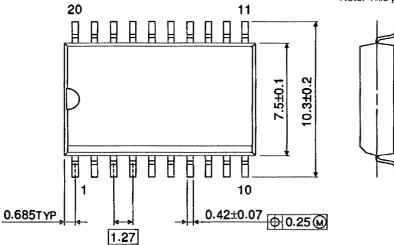


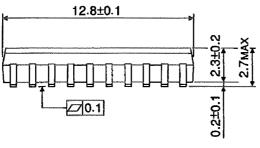
Weight: 0.22 g (typ.)

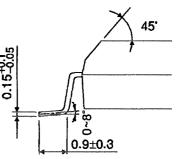
# **Package Dimensions**

SOL20-P-300-1.27







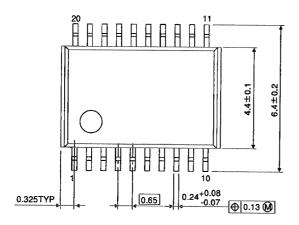


Weight: 0.46 g (typ.)

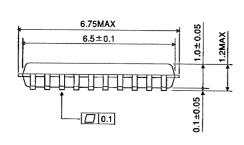
Unit: mm

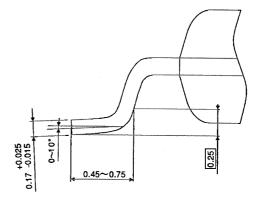
# **Package Dimensions**

TSSOP20-P-0044-0.65









Weight: 0.08 g (typ.)

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